

## High-Frequency Switchmode Controller

### Features

- 15- to 200-V Input Range
- Current-Mode Control
- Internal Start-Up Circuit
- Latched  $\overline{\text{SHUTDOWN}}$
- Soft-Start
- 1.5-MHz Error Amp

### Description

The Si9114 is a BiC/DMOS current-mode pulse width modulation (PWM) controller IC for high-frequency dc/dc converters. Single-ended topologies (forward and flyback) can be implemented at frequencies up to 1 MHz. The oscillator has an internal divide-by-two that limits the duty ratio to 50%. An oscillator sync output allows converters to be synchronized in phase as well as in frequency, in a master/slave configuration.

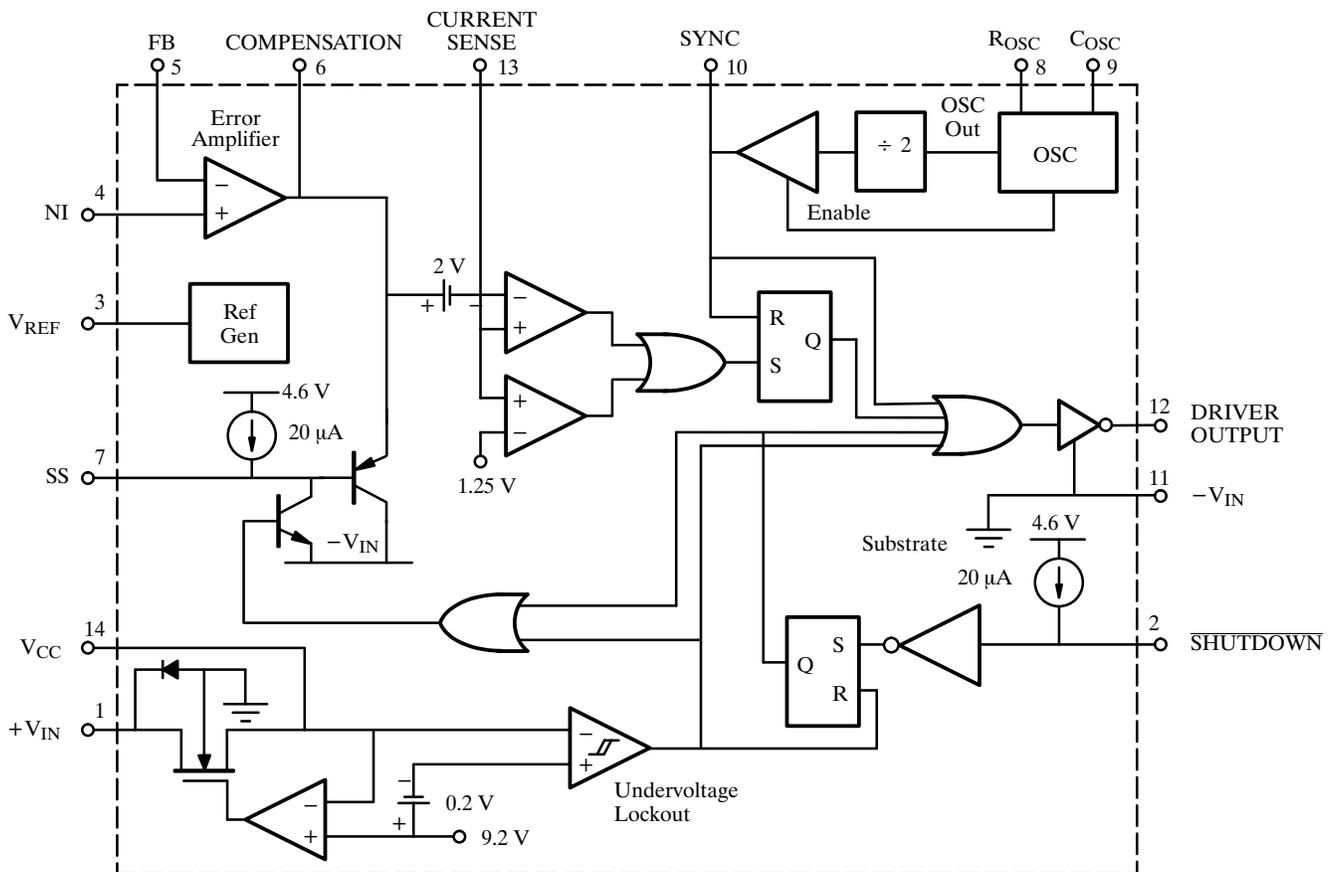
700 mA. Shoot-through current is all but eliminated to minimize supply current requirements.

The high-voltage DMOS transistor allows the IC to interface directly to bus voltages up to 200 V. Other features include a 1.5% accurate voltage reference, 1.5-MHz (min) bandwidth error amplifier, shutdown logic control, soft-start and undervoltage lockout circuits.

The Si9114 is available in 14-pin plastic DIP and SOIC packages, and is specified over the industrial, D suffix ( $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ) temperature range.

The output inverter can typically source 500 mA and sink

### Functional Block Diagram



# Si9114

## Absolute Maximum Ratings

Voltages Referenced to  $-V_{IN}$

$V_{CC}$ .....	18 V
$+V_{IN}$ (Note: $V_{CC} < +V_{IN} + 0.3$ V) .....	200 V
Logic Input ( $\overline{\text{SHUTDOWN}}$ , $\text{SYNC}$ ) .....	$-0.3$ V to $V_{CC} + 0.3$ V
Linear Inputs ( $\text{FEEDBACK}$ , $\text{SENSE}$ , $\text{SOFT-START}$ ) .....	$-0.3$ V to $V_{CC} + 0.3$ V
HV Pre-Regulator Input Current (continuous) .....	5 mA
Storage Temperature .....	$-65$ to $150^\circ\text{C}$
Operating Temperature .....	$-40$ to $85^\circ\text{C}$

Junction Temperature ( $T_J$ ) .....
 $150^\circ\text{C}$ |

Power Dissipation (Package) <sup>a</sup>	
14-Pin Plastic Dip (J Suffix) <sup>b</sup> .....	750 mW
14-Pin SOIC (Y Suffix) <sup>c</sup> .....	900 mW

Thermal Impedance ( $\Theta_{JA}$ )	
14-Pin Plastic Dip .....	$167^\circ\text{C/W}$
14-Pin SOIC .....	$140^\circ\text{C/W}$

Notes

- Device mounted with all leads soldered or welded to PC board.
- Derate 6 mW/ $^\circ\text{C}$  above  $25^\circ\text{C}$ .
- Derate 7.2 mW/ $^\circ\text{C}$  above  $25^\circ\text{C}$ .

## Recommended Operating Range

Voltages Referenced to  $-V_{IN}$

$V_{CC}$ .....	9.5 V to 16.5 V
$+V_{IN}$ .....	15 V to 200 V
$f_{OSC}$ .....	20 kHz to 2 MHz

$R_{OSC}$  .....
 56 k $\Omega$  to 1 M $\Omega$ |

$C_{OSC}$  .....
 47 pF to 200 pF |

Linear Inputs .....
 0 to  $V_{CC} - 4$  V |

Digital Inputs .....
 0 to  $V_{CC}$ |

## Specifications

Parameter	Symbol	Test Conditions Unless Otherwise Specified  Oscillator Disabled $-V_{IN} = 0$ V, $V_{CC} = 10$ V	Limits D Suffix $-40$ to $85^\circ\text{C}$			Unit
			Min <sup>b</sup>	Typ <sup>a</sup>	Max <sup>b</sup>	
<b>Reference</b>						
Output Voltage	$V_R$	OSC Disabled, $T_A = 25^\circ\text{C}$	3.94	4.0	4.06	V
		OSC Disabled Over Voltage and Temperature Ranges <sup>c</sup>	3.88	4.0	4.12	
Short Circuit Current	$I_{SREF}$	$V_{REF} = -V_{IN}$		-15	-5	mA
Load Regulation	$\Delta V_R / \Delta I_R$	$I_{REF} = 0$ to $-3$ mA		3	40	mV
<b>Oscillator</b>						
Initial Accuracy	$f_{OSC}^d$	$R_{OSC} = 374$ k $\Omega$ , $C_{OSC} = 200$ pF	90	100	110	kHz
		$R_{OSC} = 133$ k $\Omega$ , $C_{OSC} = 100$ pF	450	500	550	
Voltage Stability <sup>c</sup>	$\Delta f / f$	$R_{OSC} = 133$ k $\Omega$ , $C_{OSC} = 100$ pF $\Delta f / f = [f(16.5 \text{ V}) - f(9.5 \text{ V})] / f(9.5 \text{ V})$		1	2	%
Temperature Coefficient <sup>c</sup>	OSC TC	$-40 \leq T_A \leq 85^\circ\text{C}$ , $f_{OSC} = 100$ kHz		200	500	ppm/ $^\circ\text{C}$
Sync Output Current (Master Mode)	$I_{SYNC(M)}$	$V_{ROSC} \leq 5$ V	$\pm 1.0$	$\pm 3.0$		mA
Sync Output Current (Slave Mode)	$I_{SYNC(S)}$	$V_{ROSC} = V_{CC}$		$\pm 1$	$\pm 500$	nA

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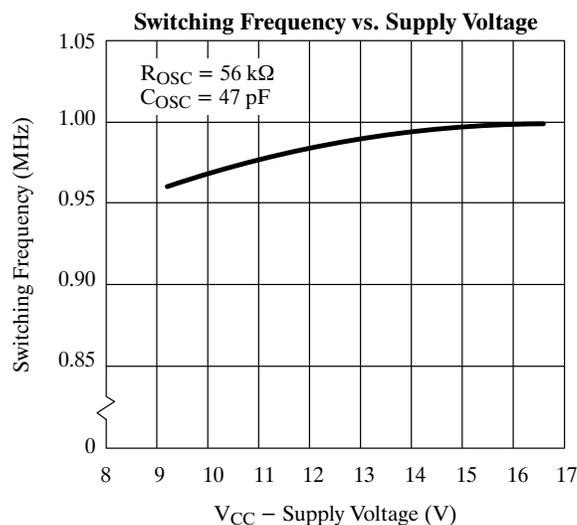
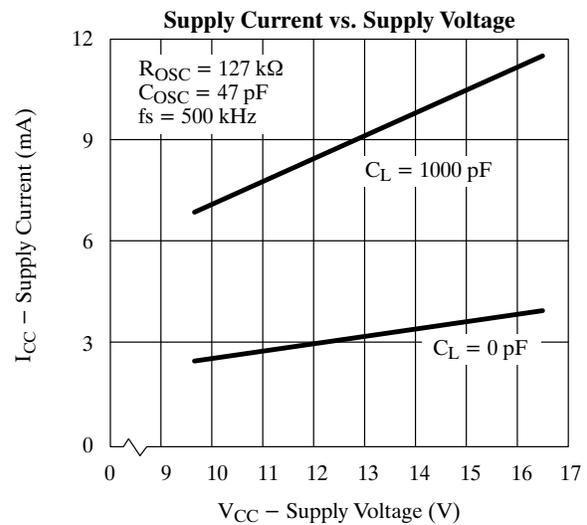
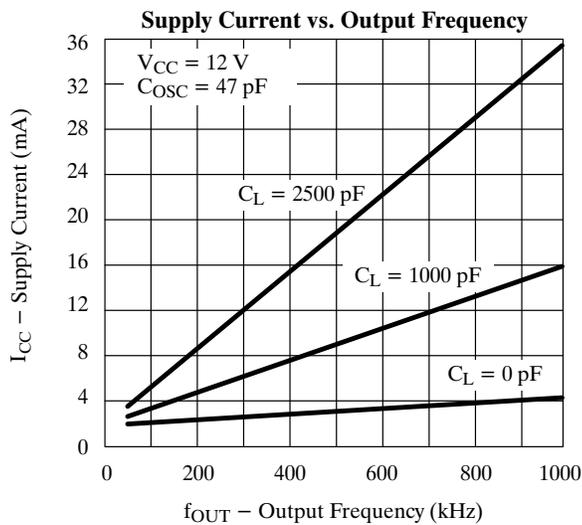
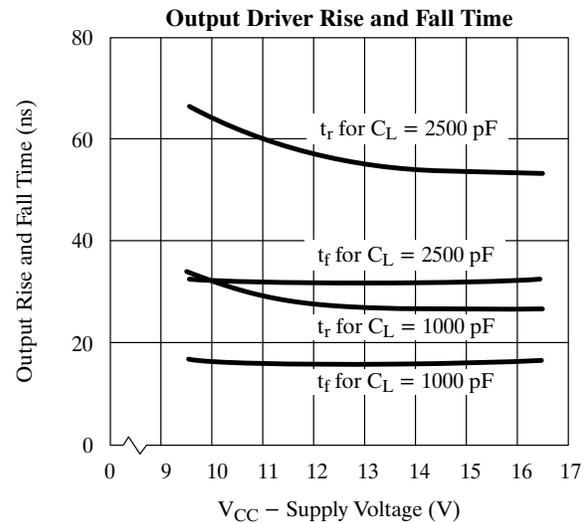
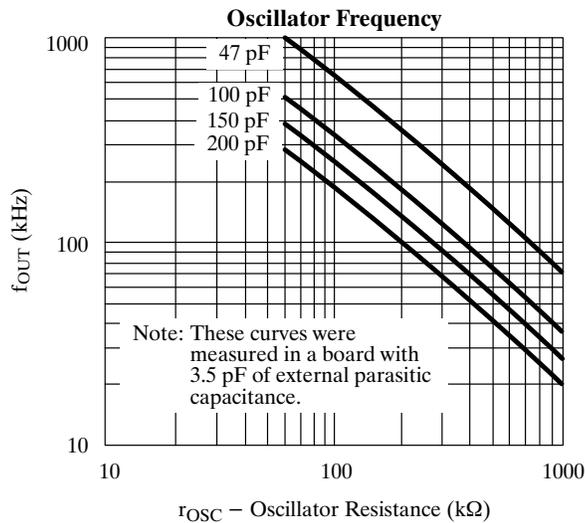
Parameter	Symbol	Test Conditions Unless Otherwise Specified  Oscillator Disabled $-V_{IN} = 0\text{ V}, V_{CC} = 10\text{ V}$	Limits D Suffix –40 to 85°C			Unit	
			Min <sup>b</sup>	Typ <sup>a</sup>	Max <sup>b</sup>		
<b>Error Amplifier (<math>C_{OSC} = -V_{IN}</math> OSC Disabled)</b>							
Input BIAS Current	$I_{FB}$	$V_{FB} = 5\text{ V}, NI = V_{REF}$		±25	±200	nA	
Input OFFSET Voltage	$V_{OS2}$			±5	±25	mV	
Open Loop Voltage Gain <sup>c</sup>	$A_{VOL}$		65	88		dB	
Unity Gain Bandwidth <sup>c</sup>	BW		1.5	2.3		MHz	
Output Current	$I_{OUT}$	Source ( $V_{FB} = 3.5\text{ V}, NI = V_{REF}$ )		-2.0	-1.0	mA	
		Sink ( $V_{FB} = 4.5\text{ V}, NI = V_{REF}$ )	1.0	4.0			
Power Supply Rejection	PSRR	$9.5\text{ V} \leq V_{CC} \leq 16.5\text{ V}$	50	88		dB	
<b>Pre-Regulator/Start-Up</b>							
Input Leakage Current	$+I_{IN}$	$+V_{IN} = 200\text{ V}, V_{CC} \geq 10\text{ V}$		<1	10	µA	
Pre-Regulator Start-Up Current	$I_{START}$	$+V_{IN} = 48\text{ V}, t_{PW} \leq 300\text{ }\mu\text{s}, V_{CC} = V_{UVLO}$	8	20		mA	
$V_{CC}$ Pre-Regulator Voltage	$V_{PR}$	$+V_{IN} = 48\text{ V}$	8.8	9.1	9.4	V	
$V_{PR} - V_{UVLO}$ (Turn-On)	$V_{DELTA}$		0.1	0.2	0.7		
Undervoltage Lockout Hysteresis	$V_{HYST}$		0.18	0.3	0.4		
<b>Supply</b>							
Supply Current	$I_{CC}$	$C_{LOAD} \leq 50\text{ pF}$	$f_{OSC} = 100\text{ kHz}$		1.3	2.5	mA
			$f_{OSC} = 500\text{ kHz}$		1.8	3.0	
<b>Protection</b>							
Current Limit Threshold Voltage	$V_{SENSE}$	$V_{FB} = 0\text{ V}, NI = V_{REF}$	1.15	1.23	1.30	V	
Current Limit Delay to Output <sup>c</sup>	$t_d$	$V_{SENSE} = 1.5\text{ V}$ , See Figure 1		70	100	ns	
$\overline{\text{SHUTDOWN}}$ Logic Threshold	$V_{SD}$			2.5	0.5	V	
$\overline{\text{SHUTDOWN}}$ Delay to Latched Output <sup>c</sup>	$t_{SD}$	See Figure 2		0.30	1.0	µs	
$\overline{\text{SHUTDOWN}}$ Pull-Up Current	$I_{SD}$	$V_{SD} = 0\text{ V}$	12	17	30	µA	
Soft-Start Current	$I_{SS}$		12	17	30		
Output Inhibit Voltage	$V_{SS(off)}$	Soft-Start Voltage to Disable Driver Output		1.7	0.5	V	
<b>MOSFET Driver</b>							
Output High Voltage	$V_{OH}$	$I_{OUT} = -10\text{ mA}$	9.85	9.9		V	
Output Low Voltage	$V_{OL}$	$I_{OUT} = 10\text{ mA}$		0.05	0.15		
Peak Output Current <sup>c</sup>	$I_{SOURCE}$	$V_{OUT} = 0\text{ V}$		-400	-200	mA	
	$I_{SINK}$	$V_{OUT} = V_{CC}$	500	700			

### Notes

- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
- Guaranteed by design, not subject to production test.
- $C_{STRAY} \leq 5\text{ pF}$  on  $C_{OSC}$ .

## Si9114

### Typical Characteristics (25°C Unless Otherwise Noted)



## Timing Waveforms

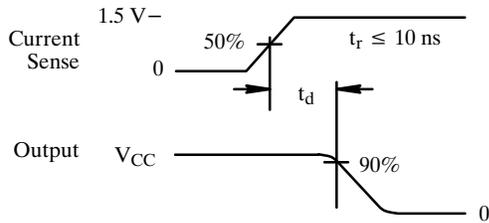


Figure 1.

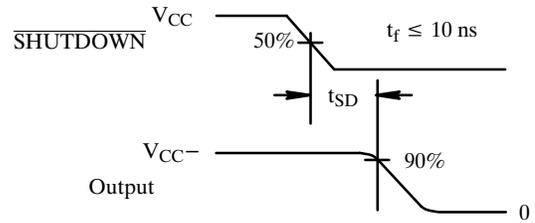
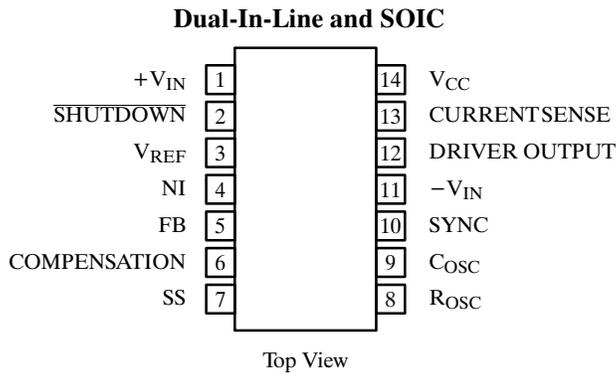


Figure 2.

## Pin Configurations



Order Numbers  
 Plastic DIP: Si9114DJ  
 SOIC: Si9114DY

## Applications

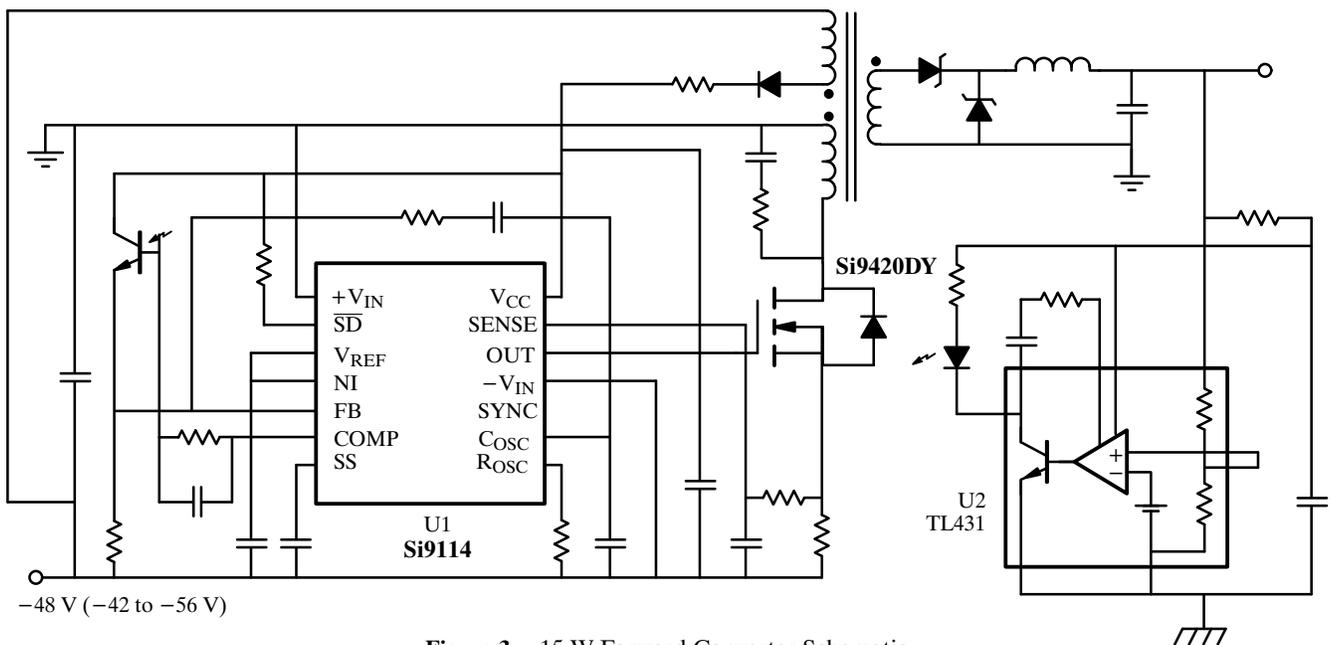


Figure 3. 15-W Forward Converter Schematic